

LTC1857/LTC1858/LTC1859

8-Channel, 12-/14-/16-Bit, 100ksps SoftSpan A/D Converters with Shutdown

FEATURES

- Sample Rate: 100ksps
- 8-Channel Multiplexer with ±25V Protection
- Single 5V Supply
- Software-Programmable Input Ranges:
 - OV to 5V, OV to 10V, ±5V or ±10V
 - Single-Ended or Differential
- ±3LSB INL for the LTC1859, ±1.5LSB INL for the LTC1858, ±1LSB INL for the LTC1857
- Power Dissipation: 40mW (Typ)
- SPI/MICROWIRE™ Compatible Serial I/O
- Power Shutdown: Nap and Sleep
- Signal-to-Noise Ratio: 87dB (Typ) for the LTC1859
- Operates with Internal or External Reference
- Internal Synchronized Clock
- 28-Pin SSOP Package

APPLICATIONS

- Industrial Process Control
- Multiplexed Data Acquisition Systems
- High Speed Data Acquisition for PCs
- Digital Signal Processing

DESCRIPTION

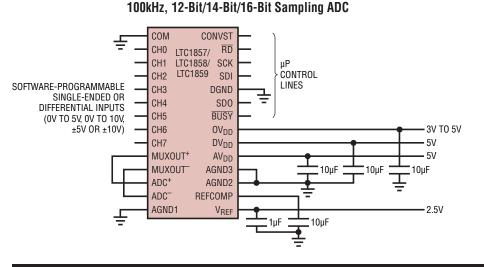
The LTC®1857/LTC1858/LTC1859 are 8-channel, low power, 12-/14-/16-bit, 100ksps, analog-to-digital converters (ADCs). These SoftSpanTM ADCs can be software-programmed for 0V to 5V, 0V to 10V, \pm 5V or \pm 10V input spans and operate from a single 5V supply. The 8-channel multiplexer can be programmed for single-ended inputs or pairs of differential inputs or combinations of both. In addition, all channels are fault protected to \pm 25V. A fault condition on any channel will not affect the conversion result of the selected channel.

An onboard high performance sample-and-hold and precision reference minimize external components. The low 40mW power dissipation is made even more attractive with two user selectable power shutdown modes. DC specifications include \pm 3LSB INL for the LTC1859, \pm 1.5LSB INL for the LTC1858 and \pm 1LSB for the LTC1857.

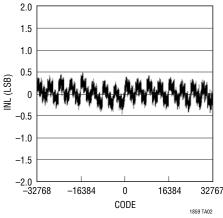
The internal clock is trimmed for 5µs maximum conversion time and the sampling rate is guaranteed at 100ksps. A separate convert start input and data ready signal (BUSY) ease connections to FIFOs, DSPs and microprocessors.

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TYPICAL APPLICATION



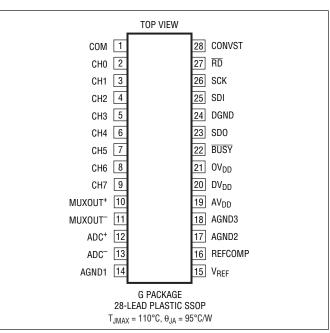
LTC1859 Typical INL Curve





(Note 1)
Supply Voltage ($OV_{DD} = DV_{DD} = AV_{DD} = V_{DD}$)6V
Ground Voltage Difference
DGND, AGND1, AGND2, AGND3±0.3V
Analog Input Voltage
ADC ⁺ , ADC ⁻
(Note 3) (AGND1 – 0.3V) to $(AV_{DD} + 0.3V)$
CH0-CH7, COM±25V
Digital Input Voltage (Note 4) (DGND – 0.3V) to 10V
Digital Output Voltage (DGND $- 0.3V$) to (DV _{DD} $+ 0.3V$)
Power Dissipation
Operating Temperature Range
LTC1857C/LTC1858C/LTC1859C 0°C to 70°C
LTC1857I/LTC1858I/LTC1859I40°C to 85°C
Storage Temperature Range65°C to 150°C
Lead Temperature (Soldering, 10 sec) 300°C

PIN CONFIGURATION



ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC1857CG#PBF	LTC1857CG#TRPBF	LTC1857CG	28-Lead Plastic SSOP	0°C to 70°C
LTC1857IG#PBF	LTC1857IG#TRPBF	LTC1857IG	28-Lead Plastic SSOP	-40°C to 85°C
LTC1858CG#PBF	LTC1858CG#TRPBF	LTC1858CG	28-Lead Plastic SSOP	0°C to 70°C
LTC1858IG#PBF	LTC1858IG#TRPBF	LTC1858IG	28-Lead Plastic SSOP	-40°C to 85°C
LTC1859CG#PBF	LTC1859CG#TRPBF	LTC1859CG	28-Lead Plastic SSOP	0°C to 70°C
LTC1859IG#PBF	LTC1859IG#TRPBF	LTC1859IG	28-Lead Plastic SSOP	-40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/ For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/



CONVERTER AND MULTPLEXER CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. MUXOUT connected to ADC inputs. (Notes 5, 6)

				LTC1857	7		LTC1858	}	I	LTC1859)	
PARAMETER	CONDITIONS		MIN	ТҮР	MAX	MIN	ТҮР	MAX	MIN	ТҮР	MAX	UNITS
Resolution			12			14			16			Bits
No Missing Codes		٠	12			14			15			Bits
Transition Noise				0.06			0.26			1		LSB _{RMS}
Integral Linearity Error	(Notes 7, 15)	٠			±1			±1.5			±3	LSB
Differential Linearity Error	(Note 15)	٠	-1		1	-1		1.5	-2		4	LSB
Bipolar Zero Error	(Note 8)	٠			±9			±17			±28	LSB
Bipolar Zero Error Drift				±0.1			±0.1			±0.1		ppm/°C
Bipolar Zero Error Match					±4			±6			±10	LSB
Unipolar Zero Error	(Note 8)	٠			±6			±15			±25	LSB
Unipolar Zero Error Drift				±1			±1			±1		ppm/°C
Unipolar Zero Error Match					±1.2			±2			±8	LSB
Bipolar Full-Scale Error	External Reference (Note 11) Internal Reference (Note 11)	•			±0.35 ±0.45			±0.15 ±0.4			±0.1 ±0.4	% %
Bipolar Full-Scale Error Drift	External Reference Internal Reference			±2.5 ±7			±2.5 ±7			±2.5 ±7		ppm/°C ppm/°C
Bipolar Full-Scale Error Match					±5			±10			±15	LSB
Unipolar Full-Scale Error	External Reference (Note 11) Internal Reference (Note 11)	•			±0.45 ±0.75			±0.25 ±0.85			±0.2 ±0.75	% %
Unipolar Full-Scale Error Drift	External Reference Internal Reference			±2.5 ±7			±2.5 ±7			±2.5 ±7		ppm/°C ppm/°C
Unipolar Full-Scale Error Match					±5			±12			±15	LSB
Input Common Mode Range	Unipolar Mode Bipolar Mode	•		0 to 10 ±10			0 to 10 ±10			0 to 10 ±10		V V
Input Common Mode Rejection Ratio				96			96			96		dB

ANALOG INPUT The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. (Note 5)

CH0 to CH7, COM	0 to 5, 0 to 10 ±5, ±10	V
	10, 110	V
ADC ⁺ , ADC ⁻ (Note 3)	0 to 2.048 0 to 4.096 ADC ⁻ ±1.024 ADC ⁻ ±2.048	V V V V
CH0 to CH7, COM Unipolar Bipolar	42 31	kΩ kΩ
MUXOUT ⁺ , MUXOUT ⁻ Unipolar Bipolar	10 5	kΩ kΩ
ADC ⁺ , ADC ⁻	Hi-Z	kΩ
CH0 to CH7, COM	5	pF
Sample Mode ADC ⁺ , ADC ⁻ 0V to 2.048V, ±1.024V 0V to 4.096V, ±2.048V	24 12	pF pF
Hold Mode ADC ⁺ , ADC ⁻	4	pF
ADC ⁺ , ADC ⁻ , CONVST = Low	• ±1	μA
-	CH0 to CH7, COM Unipolar Bipolar MUXOUT ⁺ , MUXOUT ⁻ Unipolar Bipolar ADC ⁺ , ADC ⁻ CH0 to CH7, COM Sample Mode ADC ⁺ , ADC ⁻ OV to 2.048V, ±1.024V OV to 4.096V, ±2.048V Hold Mode ADC ⁺ , ADC ⁻	O to 4.096 ADC ⁻ ±1.024 ADC ⁻ ±2.048 CH0 to CH7, COM Unipolar Bipolar MUXOUT ⁺ , MUXOUT ⁻ Unipolar Bipolar ADC ⁺ , ADC ⁻ CH0 to CH7, COM Bipolar ADC ⁺ , ADC ⁻ Hi-Z CH0 to CH7, COM Sample Mode ADC ⁺ , ADC ⁻ OV to 2.048V, ±1.024V OV to 2.048V, ±1.024V OV to 4.096V, ±2.048V Hold Mode ADC ⁺ , ADC ⁻ 4



DYNAMIC ACCURACY The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. MUXOUT connected to ADC inputs. (Notes 5, 12)

					LTC1857			LTC1858	3		LTC1859)	
SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	MIN	ТҮР	MAX	MIN	ТҮР	MAX	UNITS
S/(N + D)	Signal-to-(Noise + Distortion) Ratio	1kHz Input Signal		74			83			87		dB	
THD	Total Harmonic Distortion	1kHz Input Signal, First Five Harmonics		-101			-101			-101		dB	
	Peak Harmonic or Spurious Noise	1kHz Input Signal	1kHz Input Signal			-103		-103			-103		
	Channel-to-Channel Isolation	1kHz Input Signal			-120			-120			-120		dB
	–3dB Input Bandwidth				1			1			1		MHz
	Aperture Delay				-70			-70			-70		ns
	Aperture Jitter				60			60			60		ps
	Transient Response	Full-Scale Step (Note 9)				4			4			4	μs
	Overvoltage Recovery	(Note 13)	Note 13)					150			150		ns

INTERNAL REFERENCE CHARACTERISTICS The • denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. (Note 5)

PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{REF} Output Voltage	$I_{OUT} = 0$	•	2.475	2.5	2.525	V
V _{REF} Output Temperature Coefficient	$I_{OUT} = 0$			±10		ppm/°C
V _{REF} Output Impedance	-0.1 mA $\leq I_{OUT} \leq 0.1$ mA			8		kΩ
V _{REFCOMP} Output Voltage	$I_{OUT} = 0$			4.096		V

DIGITAL INPUTS AND DIGITAL OUTPUTS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. (Note 5)

SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS		
V _{IH}	High Level Input Voltage	V _{DD} = 5.25V		2.4			V
V _{IL}	Low Level Input Voltage	V _{DD} = 4.75V				0.8	V
I _{IN}	Digital Input Current	$V_{IN} = 0V \text{ to } V_{DD}$				±10	μA
CIN	Digital Input Capacitance				5		pF
V _{OH}	High Level Output Voltage	$V_{DD} = 4.75$ V, $I_0 = -10\mu$ A, $OV_{DD} = V_{DD}$ $V_{DD} = 4.75$ V, $I_0 = -200\mu$ A, $OV_{DD} = V_{DD}$	•	4	4.74		V V
V _{OL}	Low Level Output Voltage	$V_{DD} = 4.75V$, $I_0 = 160\mu$ A, $OV_{DD} = V_{DD}$ $V_{DD} = 4.75V$, $I_0 = 1.6$ mA, $OV_{DD} = V_{DD}$	•		0.05 0.10	0.4	V V
I _{OZ}	Hi-Z Output Leakage	$V_{OUT} = 0V$ to V_{DD} , $\overline{RD} = High$				±10	μA
C _{OZ}	Hi-Z Output Capacitance	RD = High			15		pF
ISOURCE	Output Source Current	$V_{OUT} = 0V$			-10		mA
I _{SINK}	Output Sink Current	$V_{OUT} = V_{DD}$			10		mA

POWER REQUIREMENTS The • denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$. (Note 5)

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS	
Positive Supply Voltage	(Notes 9 and 10)		4.75	5	5.25	V
Positive Supply Current Nap Mode Sleep Mode	CONVST = 0V or 5V	•		8 5.5 8	13 8 15	mA mA μA
Power Dissipation Nap Mode Sleep Mode	CONVST = 0V or 5V			40 27.5 40		mW mW μW
						105700fb



TIMING CHARACTERISTICS

RACTERISTICS The • denotes the specifications which apply over the full operating temperature

range, otherwise specifications are at $T_A = 25^{\circ}C$. (Note 5)

SYMBOL	PARAMETER	CONDITIONS		MIN	ΤΥΡ	MAX	UNITS
f _{SAMPLE(MAX)}	Maximum Sampling Frequency	Through CH0 to CH7 Inputs Through ADC ⁺ , ADC ⁻ Only	•	100	166		kHz kHz
t _{CONV}	Conversion Time				4	5	μs
t _{ACQ}	Acquisition Time	Through CH0 to CH7 Inputs Through ADC ⁺ , ADC ⁻ Only	•		1	4	μs µs
f _{SCK}	SCK Frequency	(Note 14)		0		20	MHz
t _r	SDO Rise Time	See Test Circuits			6		ns
t _f	SDO Fall Time	See Test Circuits			6		ns
t ₁	CONVST High Time			40			ns
t ₂	CONVST to BUSY Delay	C _L = 25pF, See Test Circuits			15	30	ns
t ₃	SCK Period			50			ns
t ₄	SCK High			10			ns
t ₅	SCK Low			10			ns
t ₆	Delay Time, SCK↓ to SDO Valid	C _L = 25pF, See Test Circuits			25	45	ns
t ₇	Time from Previous SDO Data Remains Valid After SCK↓	C _L = 25pF, See Test Circuits	•	5	20		ns
t ₈	SDO Valid After $\overline{RD}\downarrow$	C _L = 25pF, See Test Circuits			11	30	ns
t9	$\overline{\text{RD}}\downarrow$ to SCK Setup Time			20			ns
t ₁₀	SDI Setup Time Before SCK↑			0			ns
t ₁₁	SDI Hold Time After SCK↑			7			ns
t ₁₂	SDO Valid Before BUSY↑	\overline{RD} = Low, C _L = 25pF, See Test Circuits		5	20		ns
t ₁₃	Bus Relinquish Time	See Test Circuits			10	30	ns

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: All voltage values are with respect to ground with DGND, AGND1, AGND2 and AGND3 wired together unless otherwise noted.

Note 3: When these pin voltages are taken below ground or above $AV_{DD} = DV_{DD} = OV_{DD} = V_{DD}$, they will be clamped by internal diodes. This product can handle currents of greater than 100mA below ground or above V_{DD} without latchup.

Note 4: When these pin voltages are taken below ground they will be clamped by internal diodes. This product can handle currents of greater than 100mA below ground without latchup. These pins are not clamped to V_{DD} .

Note 5: V_{DD} = 5V, f_{SAMPLE} = 100kHz, t_r = t_f = 5ns unless otherwise specified.

Note 6: Linearity, offset and full-scale specifications apply for a singleended analog MUX input with respect to ground or ADC⁺ with respect to ADC⁻ tied to ground.

Note 7: Integral nonlinearity is defined as the deviation of a code from a straight line passing through the actual end points of the transfer curve. The deviation is measured from the center of the quantization band.

Note 9: Guaranteed by design, not subject to test.

Note 10: Recommended operating conditions.

Note 11: Full-scale bipolar error is the worst case of -FS or +FS untrimmed deviation from ideal first and last code transitions, divided by the full-scale range, and includes the effect of offset error. For unipolar full-scale error, the deviation of the last code transition from ideal, divided by the full-scale range, and includes the effect of offset error.

Note 12: All Specifications in dB are referred to a full-scale $\pm 10V$ input.

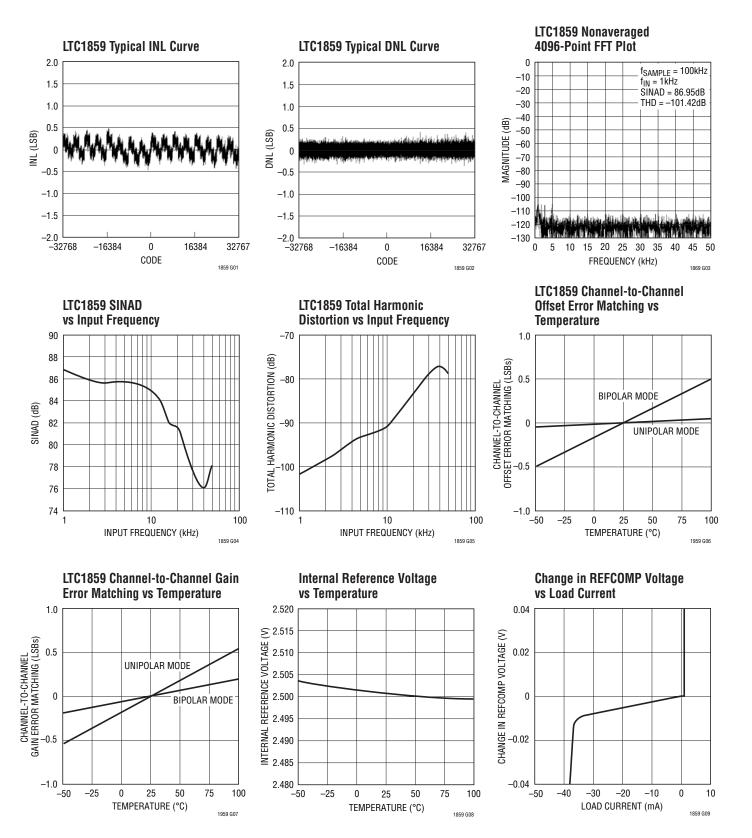
Note 13: Recovers to specified performance after (2 • FS) input overvoltage.

Note 14: t₆ of 45ns maximum allows f_{SCK} up to 10MHz for rising capture with 50% duty cycle and f_{SCK} up to 20MHz for falling capture (with 5ns setup time for the receiving logic).

Note 15: The specification is referred to the ±10V input range.



TYPICAL PERFORMANCE CHARACTERISTICS

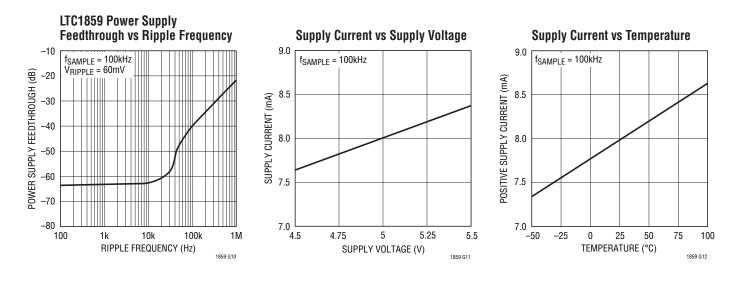


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TYPICAL PERFORMANCE CHARACTERISTICS



PIN FUNCTIONS

COM (Pin 1): Common Input. This is the reference point for all single-ended inputs. It must be free of noise and is usually connected to the analog ground plane.

CHO (Pin 2): Analog MUX Input.

CH1 (Pin 3): Analog MUX Input.

CH2 (Pin 4): Analog MUX Input.

CH3 (Pin 5): Analog MUX Input.

CH4 (Pin 6): Analog MUX Input.

CH5 (Pin 7): Analog MUX Input.

CH6 (Pin 8): Analog MUX Input.

CH7 (Pin 9): Analog MUX Input.

MUXOUT⁺(**Pin 10**): Positive MUX Output. Output of the analog multiplexer. Connect to ADC⁺ for normal operation.

MUXOUT⁻ (**Pin 11**): Negative MUX Output. Output of the analog multiplexer. Connect to ADC⁻ for normal operation.

ADC+ (Pin 12): Positive Analog Input to the Analog-to-Digital Converter.

ADC⁻ (Pin 13): Negative Analog Input to the Analog-to-Digital Converter. AGND1 (Pin 14): Analog Ground.

 V_{REF} (Pin 15): 2.5V Reference Output. Bypass to analog ground with a 1µF tantalum capacitor.

REFCOMP (Pin 16): Reference Buffer Output. Bypass to analog ground with a 10μ F tantalum and a 0.1μ F ceramic capacitor. Nominal output voltage is 4.096V.

AGND2 (Pin 17): Analog Ground.

AGND3 (Pin 18): Analog Ground. This is the substrate connection.

 AV_{DD} (Pin 19): 5V Analog Supply. Bypass to analog ground with a 0.1µF ceramic and a 10µF tantalum capacitor.

 DV_{DD} (Pin 20): 5V Digital Supply. Bypass to digital ground with a 0.1µF ceramic and a 10µF tantalum capacitor.

 OV_{DD} (Pin 21): Positive Supply for the Digital Output Buffers (3V to 5V). Bypass to digital ground with a 0.1µF ceramic and a 10µF tantalum capacitor.

BUSY (Pin 22): Output shows converter status. It is low when a conversion is in progress.

SDO (Pin 23): Serial Data Output.

PIN FUNCTIONS

DGND (Pin 24): Digital Ground.

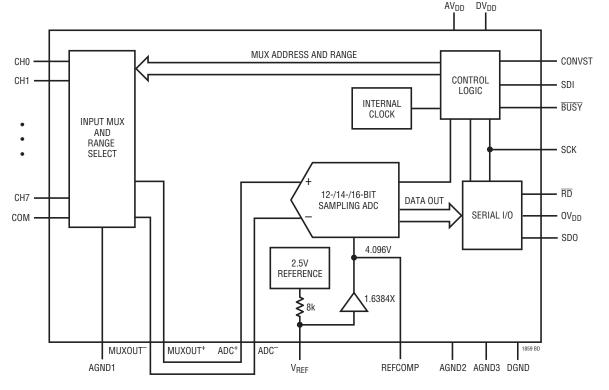
SDI (Pin 25): Serial Data Input. SDI will ignore clocked data while RD is high.

SCK (Pin 26): Serial Data Clock.

RD (Pin 27): Read Input. This active low signal enables the digital output pin SDO.

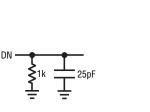
CONVST (Pin 28): Conversion Start. This active high signal starts a conversion on its rising edge.

FUNCTIONAL BLOCK DIAGRAM



TEST CIRCUITS

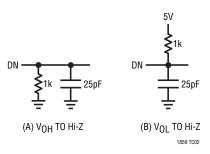




(a) Hi-z to v_{OH} and v_{OL} to v_{OH}

(B) Hi-Z TO V_{OL} AND V_{OH} TO V_{OL} 1859 TC01

Load Circuits for Output Float Delay



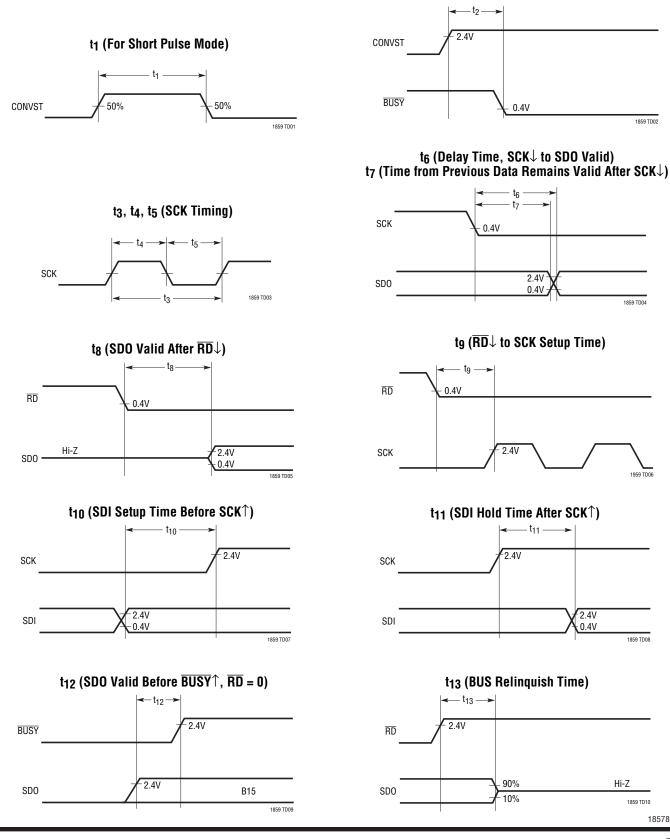




t₂ (CONVST to BUSY Delay)

1859 TD02

TIMING DIAGRAMS







OPERATION

OVERVIEW

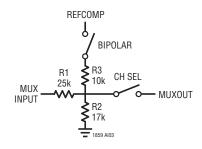
The LTC1857/LTC1858/LTC1859 are innovative, multichannel ADCs that provide software-selectable input ranges for each of their eight input channels. Using on-chip resistors and switches, it provides an attenuation and offset that can be programmed for each channel on the fly. The precisely trimmed attenuators ensure accurate input ranges. Because they precede the multiplexer, errors due to multiplexer on-resistance are eliminated.

The input word that selects the input channel also selects the desired input range for that channel. The available ranges are 0V to 5V, 0V to 10V (unipolar), \pm 5V and \pm 10V (bipolar). They are achieved with the ADC running on a single 5V supply. In addition to the range selection, single-ended or differential inputs may be selected for each channel or pair of channels. Finally, overrange protection is provided for unselected channels. An overrange condition on an unused channel will not affect the conversion result on the selected channel.

CONVERSION DETAILS

The LTC1857/LTC1858/LTC1859 use a successive approximation algorithm and an internal sample-and-hold circuit to convert an analog signal to a 12-/14-/16-bit serial output respectively. The ADCs are complete with a precision reference and an internal clock. The control logic provides easy interface to microprocessors and DSPs. (Please refer to the Digital Interface section for the data format.)

The analog signals applied at the MUX input channels are rescaled by the resistor divider network formed by R1, R2 and R3 as shown below. The rescaled signals appear on the MUXOUT (Pins 10, 11) which are also connected to the ADC inputs (Pins 12, 13) under normal operation.



Before starting a conversion, an 8-bit data word is clocked into the SDI input on the first eight rising SCK edges to select the MUX address, input range and power down mode. The ADC enters acquisition mode on the falling edge of the sixth clock in the 8-bit data word and ends on the rising edge of the CONVST signal which also starts a conversion (see Figure 7). A minimum time of 4µs will provide enough time for the sample-and-hold capacitors to acquire the analog signal. Once a conversion cycle has begun, it cannot be restarted.

During the conversion, the internal differential 12-/14-/16-bit capacitive DAC output is sequenced by the SAR from the most significant bit (MSB) to the least significant bit (LSB). The input is successively compared with the binary weighted charges supplied by the differential capacitive DAC. Bit decisions are made by a high speed comparator. At the end of a conversion, the DAC output balances the analog input (ADC⁺ – ADC⁻). The SAR contents (a 16-bit data word) which represents the difference of ADC⁺ and ADC⁻ are loaded into the 12-/14-/16-bit shift register.

DRIVING THE ANALOG INPUTS

The nominal input ranges for the LTC1857/LTC1858/ LTC1859 are OV to 5V. OV to 10V. ±5V and ±10V and the MUX inputs are overvoltage protected to $\pm 25V$. The input impedance is typically $42k\Omega$ in unipolar mode and $31k\Omega$ in bipolar mode, therefore, it should be driven with a low impedance source. Wideband noise coupling into the input can be minimized by placing a 3000pF capacitor at the input as shown in Figure 2. An NPO-type capacitor gives the lowest distortion. Place the capacitor as close to the device input pin as possible. If an amplifier is to be used to drive the input, care should be taken to select an amplifier with adequate accuracy, linearity and noise for the application. The following list is a summary of the op amps that are suitable for driving the LTC1857/LTC1858/LTC1859. More detailed information is available in the Linear Technology data books and online at www.linear.com.

LT®1007: Low noise precision amplifier. 2.7mA supply current $\pm 5V$ to $\pm 15V$ supplies. Gain bandwidth product 8MHz. DC applications.





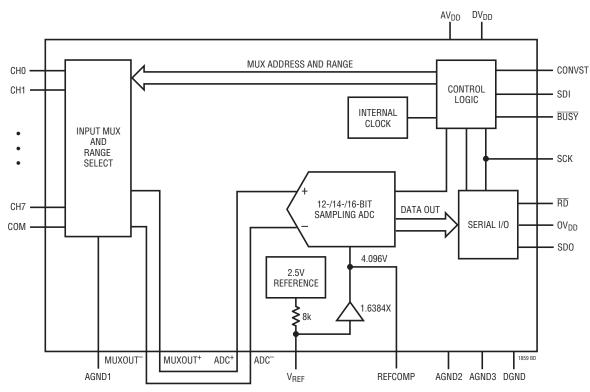


Figure 1. LTC1857/LTC1858/LTC1859 Simplified Equivalent Circuit

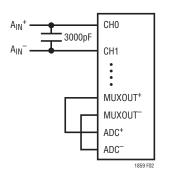


Figure 2. Analog Input Filtering

LT1227: 140MHz video current feedback amplifier. 10mA supply current. \pm 5V to \pm 15V supplies. Low noise and low distortion.

LT1468/LT1469: Single and dual 90MHz, 16-bit accurate op amp. Good AC/DC specs.

LT1677: Single, low noise op amp. Rail-to-rail input and output. Up to $\pm 15V$ supplies.

LT1792: Single, low noise JFET input op amp, $\pm 5V$ supplies.

LT1793: Single, low noise JFET input op amp, 10pA bias current, $\pm 5V$ supplies.

LT1881/LT1882: Dual and quad, 200pA bias current, rail-to-rail output op amps. Up to $\pm 15V$ supplies.

LT1844/LT1885: Dual and quad, 400pA bias current, rail-to-rail output op amps. Up to $\pm 15V$ supplies. Faster response and settling time.

INTERNAL VOLTAGE REFERENCE

The LTC1857/LTC1858/LTC1859 have an on-chip, temperature compensated, curvature corrected, bandgap reference, which is factory trimmed to 2.50V. The full-scale range of the LTC1857/LTC1858/LTC1859 is equal to \pm 5V, OV to 5V, \pm 10V or 0V to 10V. The output of the reference is connected to the input of a gain of 1.6384x buffer through an 8k resistor (see Figure 3). The input to the buffer or



the output of the reference is available at V_{REF} (Pin 15). The internal reference can be overdriven with an external reference if more accuracy is needed. The buffer output drives the internal DAC and is available at REFCOMP (Pin 16). The REFCOMP pin can be used to drive a steady DC load of less than 2mA. Driving an AC load is not recommended because it can cause the performance of the converter to degrade.

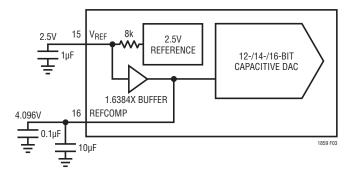


Figure 3. Internal or External Reference Source

For minimum code transition noise the V_{REF} pin and the REFCOMP pin should each be decoupled with a capacitor to filter wideband noise from the reference and the buffer.

UNIPOLAR / BIPOLAR OPERATION

Figure 4a shows the ideal input/output characteristics for the LTC1859. The code transitions occur midway

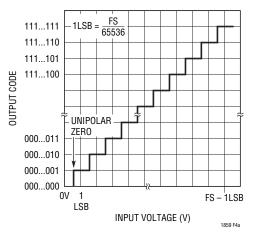


Figure 4a. Unipolar Transfer Characteristics (UNI = 1)

between successive integer LSB values (i.e., 0.5LSB, 1.5LSB, 2.5LSB, ... FS – 1.5LSB). The output code is natural binary with 1LSB = FS/65536. Figure 4b shows the input/output transfer characteristics for the bipolar mode in two's complement format.

FULL SCALE AND OFFSET

For bipolar zero error, apply -0.5LSB (actual voltage will vary with input span selected) to the "+" input and adjust the offset at the "-" input until the output code flickers between 0000 0000 0000 0000 and 1111 1111 1111 1111 for the LTC1859, between 00 0000 0000 and

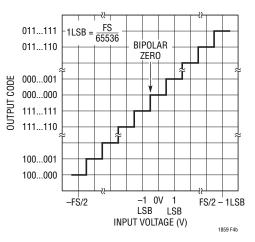


Figure 4b. Bipolar Transfer Characteristics (UNI = 0)





11 1111 1111 1111 for the LTC1858 and between 0000 0000 0000 and 1111 1111 1111 for the LTC1857.

For bipolar inputs, an input voltage of FS -1.5LSBs should be applied to the "+" input and the appropriate reference adjusted until the output code flickers between 0111 1111 1111 1110 and 0111 1111 1111 1111 for the LTC1859, between 01 1111 1111 1110 and 01 1111 1111 1111 for the LTC1858 and between 0111 1111 1110 and 0111 1111 1111 for the LTC1857.

These adjustments as well as the factory trims affect all channels. The channel-to-channel offset and gain error matching are guaranteed by design to meet the specifications in the Converter Characteristics table.

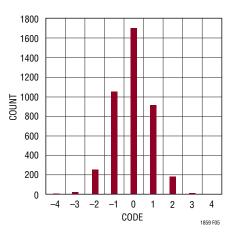
DC PERFORMANCE

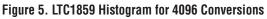
One way of measuring the transition noise associated with a high resolution ADC is to use a technique where a DC signal is applied to the input of the MUX and the resulting output codes are collected over a large number of conversions. For example in Figure 5 the distribution of output code is shown for a DC input that has been digitized 4096 times. The distribution is Gaussian and the RMS code transition is about 1LSB for the LTC1859.

DIGITAL INTERFACE

Internal Clock

The ADC has an internal clock that is trimmed to achieve a typical conversion time of 4μ s. No external adjustments are required and, with the maximum acquisition time of 4μ s, throughput performance of 100ksps is assured.





3V Input/Output Compatible

The LTC1857/LTC1858/LTC1859 operate on a 5V supply, which makes the devices easy to interface to 5V digital systems. These devices can also interface to 3V digital systems: the digital input pins (SCK, SDI, CONVST and RD) of the LTC1857/LTC1858/LTC1859 recognize 3V or 5V inputs. The LTC1857/LTC1858/LTC1859 have a dedicated output supply pin (OVP) that controls the output swings of the digital output pins (SDO, BUSY) and allows the part to interface to either 3V or 5V digital systems. The output is two's complement binary for bipolar mode and offset binary for unipolar mode.

Timing and Control

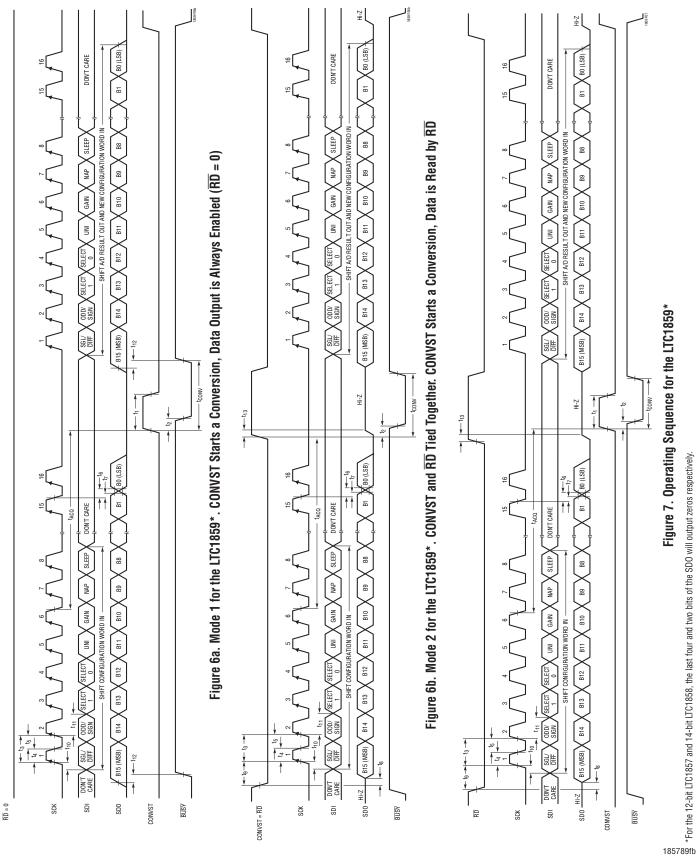
Conversion start and data read are controlled by two digital inputs: CONVST and RD. To start a conversion and put the sample-and-hold into the hold mode bring CONVST high for no less than 40ns. Once initiated it cannot be restarted until the conversion is complete. Converter status is indicated by the BUSY output and this is low while the conversion is in progress.

Figures 6a and 6b show two different modes of operation for the LTC1859. For the 12-bit LTC1857 and 14-bit LTC1858, the last four and two bits of the SDO will output zeros respectively. In mode 1 (Figure 6a), RD is tied low. The rising edge of CONVST starts the conversion. The data outputs are always enabled. The MSB of the data output is available after the conversion. In mode 2 (Figure 6b), CONVST and RD are tied together. The rising edge of the CONVST signal starts the conversion. Data outputs are in 185789tb



LTC1857/LTC1858/LTC1859

APPLICATIONS INFORMATION



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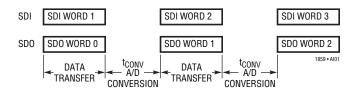


three-state at this time. When the conversion is complete (BUSY goes high), CONVST and RD go low to enable the data output for the previous conversion.

SERIAL DATA INPUT (SDI) INTERFACE

The LTC1857/LTC1858/LTC1859 communicate with microprocessors and other external circuitry via a synchronous, full duplex, 3-wire serial interface (see Figure 7). The shift clock (SCK) synchronizes the data transfer with each bit being transmitted on the falling SCK edge and captured on the rising SCK edge in both transmitting and receiving systems. The data is transmitted and received simultaneously (full duplex).

An 8-bit input word is shifted into the SDI input which configures the LTC1857/LTC1858/LTC1859 for the next conversion. Simultaneously, the result of the previous conversion is output on the SDO line. At the end of the data exchange the requested conversion begins by applying a rising edge on CONVST. After t_{CONV}, the conversion is complete and the results will be available on the next data transfer cycle. As shown below, the result of a conversion is delayed by one conversion from the input word requesting it.



INPUT DATA WORD

The LTC1857/LTC1858/LTC18598-bit data word is clocked into the SDI input on the first eight rising SCK edges. Further inputs on the SDI pin are then ignored until the next conversion. The eight bits of the input word are defined as follows:

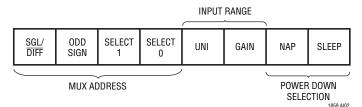


Table 1 Multiplexer Channel Selection

	I. Mu	<u> </u>		-					-						,	-				-			-
М	UX ADD	RES	S	DIFFERENTIAL CHANNEL SELECTION							M	UX ADD	RESS	SINGLE-ENDED CHANNEL SELECTION									
SGL/ DIFF	ODD Sign	SEL 1	ECT 0	0	1	2	3	4	5	6	7	SGL/ DIFF	ODD Sign	SELECT 1 0	0	1	2	3	4	5	6	7	COM
0	0	0	0	+	-							1	0	0 0	+								-
0	0	0	1			+	_					1	0	0 1			+						_
0	0	1	0					+	_			1	0	1 0					+				-
0	0	1	1							+	-	1	0	1 1							+		_
0	1	0	0	-	+							1	1	0 0		+							_
0	1	0	1			_	+					1	1	0 1				+					_
0	1	1	0					-	+			1	1	1 0						+			_
0	1	1	1							_	+	1	1	1 1								+	-

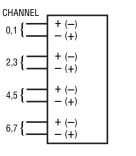
4 Differential

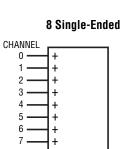
0,1

2,3

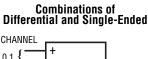
45

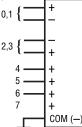
6,7





COM (-)







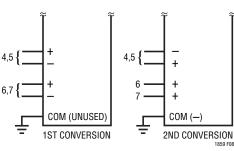


Figure 8. Examples of Multiplexer Options on the LTC1857/LTC1858/LTC1859



MUX ADDRESS

The first four bits of the input word assign the MUX configuration for the requested conversion. For a given channel selection, the converter will measure the voltage between the two channels indicated by the + and – signs in the selected row of Table 1. Note that in differential mode (SGL/DIFF = 0) measurements are limited to four adjacent input pairs with either polarity. In single-ended mode, all input channels are measured with respect to COM. Both the "+" and "-" inputs are sampled simultaneously so common mode noise is rejected.

INPUT RANGE (UNI, GAIN)

The fifth and sixth input bits (UNI, GAIN) determine the input range for the conversion. When UNI is a logical one, a unipolar conversion will be performed. When UNI is a logical zero, a bipolar conversion will result. The GAIN input bit determines the input span for the conversion. When GAIN is a logical one, either OV to 10V or \pm 10V input spans will be selected depending on UNI. When GAIN is a logical zero, either OV to 5V or \pm 5V input spans will be chosen. The input ranges for different UNI and GAIN inputs are shown in Table 2.

Table 2. Input Range Selection

UNI	GAIN	INPUT RANGE
0	0	±5V
1	0	0V to 5V
0	1	±10V
1	1	0V to 10V

POWER DOWN SELECTION (NAP, SLEEP)

The last two bits of the input word (Nap and Sleep) determine the power shutdown mode of the LTC1857/LTC1858/ LTC1859. See Table 3. Nap mode is selected when Nap = 1 and Sleep = 0. The previous conversion result will be clocked out and a conversion will occur before entering the Nap mode. The Nap mode starts at the end of the conversion which is indicated by the rising edge of the $\overline{\text{BUSY}}$ signal. Nap mode lasts until the falling edge of the 2nd SCK (see Figure 9). Automatic nap will be achieved if Nap = 1 is selected each time an input word is written to the ADC.

Table	3.	Power	Down	Selection
-------	----	-------	------	-----------

NAP	SLEEP	POWER DOWN MODE
0	0	Power On
1	0	Nap
Х	1	Sleep

Sleep mode will occur when Sleep = 1 is selected, regardless of the selection of the Nap input. The previous conversion result can be clocked out and the Sleep mode will start on the falling edge of the last (16th) SCK. Notice that the CONVST should stay either high or low in sleep mode (see Figure 10). To wake up from the sleep mode, apply a rising edge on the CONVST signal and then apply Sleep = 0 on the next SDI word and the part will wake up on the falling edge of the last (16th) SCK (see Figure 11).

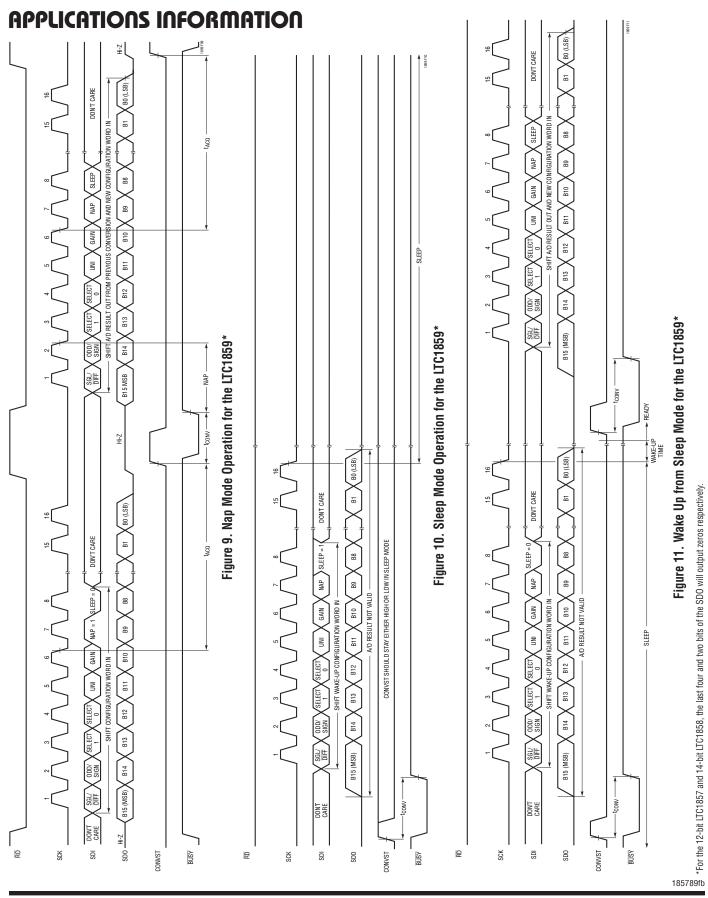
In Sleep mode, all bias currents are shut down and only the power on reset circuit and leakage currents (about $10\mu A$) remain. Sleep mode wake-up time is dependent on the value of the capacitor connected to the REFCOMP (Pin 16). The wake-up time is typically 40ms with the recommended $10\mu F$ capacitor connected on the REFCOMP pin.

DYNAMIC PERFORMANCE

FFT (Fast Fourier Transform) test techniques are used to test the ADC's frequency response, distortion and noise at the rated throughput. By applying a low distortion sine wave and analyzing the digital output using an FFT algorithm, the ADC's spectral content can be examined for frequencies outside the fundamental. Figure 12 shows a typical LTC1859 FFT plot which yields a SINAD of 87dB and THD of -101dB.



185789fb



LTC1857/LTC1858/LTC1859

TECHNOLOGY

For more information www.linear.com/LTC1857

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SIGNAL-TO-NOISE RATIO

The Signal-to-Noise and Distortion Ratio (SINAD) is the ratio between the RMS amplitude of the fundamental input frequency to the RMS amplitude of all other frequency components at the A/D output. The output is band limited to frequencies from above DC and below half the sampling frequency. Figure 12 shows a typical SINAD of 87dB with a 100kHz sampling rate and a 1kHz input.

TOTAL HARMONIC DISTORTION

Total Harmonic Distortion (THD) is the ratio of the RMS sum of all harmonics of the input signal to the fundamental itself. The out-of-band harmonics alias into the frequency band between DC and half the sampling frequency. THD is expressed as:

$$THD = 20log \frac{\sqrt{V_2^2 + V_3^2 + V_4^2 ... + V_N^2}}{V_1}$$

where V_1 is the RMS amplitude of the fundamental frequency and V_2 through V_N are the amplitudes of the second through Nth harmonics.

BOARD LAYOUT, POWER SUPPLIES AND DECOUPLING

Wire wrap boards are not recommended for high resolution or high speed A/D converters. To obtain the best performance from the LTC1857/LTC1858/LTC1859, a printed circuit board is required. Layout for the printed circuit board should ensure the digital and analog signal lines are separated as much as possible. In particular, care should be taken not to run any digital track alongside an analog signal track or underneath the ADC. The analog input should be screened by AGND.

In applications where the MUX is connected to the ADC, it is possible to get noise coupling into the ADC from the trace connecting the MUXOUT to the ADC. Therefore, reducing the length of the traces connecting the MUXOUT pins (Pins 10, 11) to the ADC pins (Pins 12, 13) can minimize the problem. The unused MUX inputs should be grounded to prevent noise coupling into the inputs.

Figure 13 shows the power supply grounding that will help obtain the best performance from the 12-bit/14-bit/16-bit ADCs. Pay particular attention to the design of the analog and digital ground planes. The DGND pin of the LTC1857/

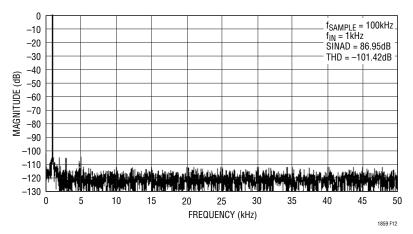


Figure 12. LTC1859 Nonaveraged 4096 Point FFT Plot



LTC1858/LTC1859 can be tied to the analog ground plane. Placing the bypass capacitor as close as possible to the power supply pins, the reference and reference buffer output is very important. Low impedance common returns for these bypass capacitors are essential to low noise operation of the ADC, and the foil width for these tracks should be as wide as possible. Also, since any potential difference in grounds between the signal source and ADC appears as an error voltage in series with the input signal, attention should be paid to reducing the ground circuit impedance as much as possible. The digital output latches and the onboard sampling clock have been placed on the digital ground plane. The two ground planes are tied together at the power supply ground connection.

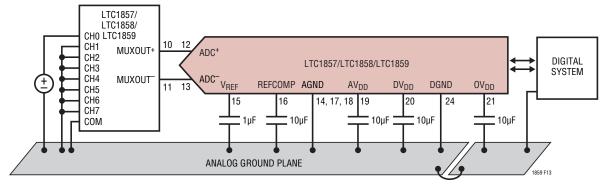
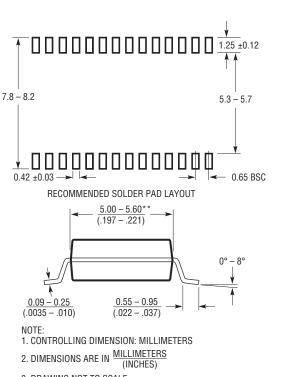


Figure 13. Power Supply Grounding Practice



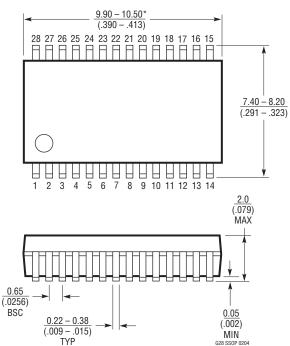
PACKAGE DESCRIPTION

Please refer to http://www.linear.com/designtools/packaging/ for the most recent package drawings.



3. DRAWING NOT TO SCALE

- *DIMENSIONS DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .152mm (.006") PER SIDE
- **DIMENSIONS DO NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED .254mm (.010") PER SIDE



28-Lead Plastic SSOP (5.3mm) (Reference LTC DWG # 05-08-1640)

G Package





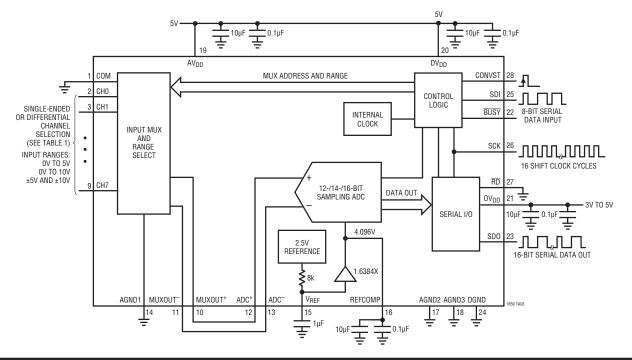
REVISION HISTORY (Revision history begins at Rev B)

REV	DATE	DESCRIPTION	PAGE NUMBER
В	06/15	Added part marking.	2
		Updated SDI pin functionality description.	8



TECHNOLOGY

TYPICAL APPLICATION



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS	
Sampling ADCs			
LTC1417	14-Bit, 400ksps Serial ADC	5V or ±5V, 20mW, 81dB SINAD and –95dB THD	
LTC1418	14-Bit, 200ksps, Single 5V or ±5V ADC	15mW, Serial/Parallel I/O	
LTC1604	16-Bit, 333ksps, ±5V ADC	90dB SINAD, 220mW Power Dissipation, Pin Compatible with LTC1608	
LTC1605	16-Bit, 100ksps, Single 5V ADC	±10V Inputs, 55mW, Byte or Parallel I/O, Pin Compatible with LTC1606	
LTC1606	16-Bit, 250ksps, Single 5V ADC	±10V Inputs, 75mW, Byte or Parallel I/O, Pin Compatible with LTC1605	
LTC1608	16-Bit, 500ksps, ±5V ADC	90dB SINAD, 270mW Power Dissipation, Pin Compatible with LTC1604	
LTC1609	16-Bit, 200ksps Serial ADC	Configurable Unipolar/Bipolar Input, Single 5V Supply	
LTC1850/LTC1851	10-Bit/12-Bit, 8-Channel, 1.25Msps ADC	Programmable MUX and Sequencer, Parallel I/O	
LTC1852/LTC1853	10-Bit/12-Bit, 8-Channel, 400ksps ADC	Single 3V-5V, Programmable MUX and Sequencer, Parallel I/O	
LTC1864/LTC1865	16-Bit, 1-/2-Channel, 250ksps ADC in MSOP	Single 5V Supply, 850µA with Autoshutdown	
LTC1864L/LTC1865L	3V, 16-Bit, 1-/2-Channel, 150ksps ADC in MSOP	Single 3V Supply, 450µA with Autoshutdown	
DACs		·	
LTC1588/LTC1589/ LTC1592	12-/14-/16-Bit, Serial, SoftSpan I _{OUT} DACs	Software-Selectable Spans, ±1LSB INL/DNL	
LTC1595	16-Bit Serial Multiplying I _{OUT} DAC in SO-8	±1LSB Max INL/DNL, Low Glitch, DAC8043 16-Bit Upgrade	
LTC1596	16-Bit Serial Multiplying I _{OUT} DAC	±1LSB Max INL/DNL, Low Glitch, AD7543/DAC8143 16-Bit Upgrade	
LTC1597	16-Bit Parallel, Multiplying DAC	±1LSB Max INL/DNL, Low Glitch, 4 Quadrant Resistors	
LTC1650	16-Bit Serial V _{OUT} DAC	Low Power, Low Gritch, 4-Quadrant Multiplication	
Op Amps	·		
LT1468/LT1469	Single/Dual 90MHz, 22V/µs, 16-Bit Accurate Op Amp	Low Input Offset : 75µV/125µV	

